

Paper
Case filed 11-4-93
with the case.

BOX A F

IN THE UNITED STATES PATENT AND TRADE MARKS OFFICE

Applicant: R.C. Foss et al
Serial No: 07/680,747
Filed: April 5, 1991
Title: METHOD FOR DRAM SENSING CURRENT CONTROL
Art Unit: 2502
Examiner: T. Dinh
Our File: 628.30050X00

~~11/2 (N)~~
~~(E)~~

~~FJ~~

~~10-25-93~~
Pre Amend

14/B

12-30-93

UOI 20 1993

~~5-1~~

The Commissioner of Patents
and Trade Marks,
Washington, D.C., 20231
U.S.A.

October 18, 1993

Dear Sir:

This is in response to the official action dated
May 17th, 1993 in the above-identified application.

Please amend the claims as follows:

- Subt
C1
1. (Amended) A dynamic random access memory
(DRAM) comprising:
- (a) a plurality of bit storage capacitors,
 - (b) a folded bit line comprised of a complementary
bit line pair for receiving charge stored on one of said
capacitors, having bit line capacitance,
 - (c) a sense amplifier having a pair of sense nodes
for sensing a voltage differential across said sense nodes,
 - (d) high resistance controllable current leakage
imperfect isolating means connecting said bit line to said
- B1

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